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 APPLICATION NO.
 FILING DATE
 FIRST NAMED INVENTOR
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 09/482,859
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 HAGIWARA
 H
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020457 IM22/0922 ANTONELLI TERRY STOUT AND KRAUS SUITE 1800 1300 NORTH SEVENTEENTH STREET ARLINGTON VA 22209 EXAMINER

CHU, J

ART UNIT PAPER NUMBER

1752

de d'Amildia

DATE MAILED:

09/22/00

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

PTO-90C (Rev. 2/95)

U.S. G.P.O. 2000 ; 485-188/25268

1- File Copy

Office Action Summary

Application No. 09/482,859

Applicant(s)

HAGIWARA ET AL

Examiner

John Chu

Group Art Unit 1752



X Responsive to communication(s) filed on Aug 31, 2000	·
☐ This action is FINAL .	
☐ Since this application is in condition for allowance except for form in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D.	
A shortened statutory period for response to this action is set to exp is longer, from the mailing date of this communication. Failure to resapplication to become abandoned. (35 U.S.C. § 133). Extensions of 37 CFR 1.136(a).	spond within the period for response will cause the
Disposition of Claims	
	is/are pending in the application.
Of the above, claim(s) 10-19	is/are withdrawn from consideration.
Claim(s)	
☑ Claim(s) 1-9	is/are rejected.
☐ Claim(s)	
Claims are subject to restriction or election requirement.	
Application Papers	
☐ See the attached Notice of Draftsperson's Patent Drawing Rev	riew, PTO-948.
☐ The drawing(s) filed on is/are objected to	by the Examiner.
☐ The proposed drawing correction, filed on	_ is □approved □disapproved.
☐ The specification is objected to by the Examiner.	
☐ The oath or declaration is objected to by the Examiner.	
Priority under 35 U.S.C. § 119	
Acknowledgement is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d).	
received.	
received in this national stage application from the International Bureau (PCT Rule 17.2(a)).	
*Certified copies not received: Acknowledgement is made of a claim for domestic priority under 35 U.S.C. § 119(e).	
Acknowledgement is made of a claim for domestic priority on	der 33 0.3.C. \$ 113(e).
Attachment(s)	
Notice of References Cited, PTO-892 Information Disclosure Statement(s), PTO-1449, Paper No(s). 2 and 6	
☐ Interview Summary, PTO-413	
☐ Notice of Draftsperson's Patent Drawing Review, PTO-948	
☐ Notice of Informal Patent Application, PTO-152	
SEE OFFICE ACTION ON THE F	OLLOWING PAGES
OLL OFFICE ACTION ON THE FOLLOWING FRANCE	

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DETAILED ACTION

- 1. This Office action is in response to the election and IDS received August 31, 2000.
- 2. Claims 10-19 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim. Election was made without traverse in Paper No. 5.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 1-9 are rejected under 35 U.S.C. 103(a) as being unpatentable over OHBAYASHI ET AL '391 or ALDRICH ET AL.

The claimed invention is drawn to a semiconductor device, comprising:

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a semiconductor substrate; and a polyimide film overlying the semiconductor substrate, wherein said polyimide film includes a polyimide material formed from an oxydiphthalic acid or acid anhydride thereof as a reactant.

OHBAYASHI ET AL discloses a photosensitive resin composition comprising a polyamic acid (col. 2, lines 63 - col. 6, line 21), an acryl compound having an amino group (col., 6, lines 29-44), an azide compound (col.7, 38 - col. 8, line 48) and a photoinitiator (col. 9, lines 14-20). This disclosure suggests the claimed composition used in the claimed process lacking only an explicit disclosure using a polyamic acid made by an oxydiphthalic dianhydride and a diamine.

It would have been *prima facie* obvious to one of ordinary skill in the requisite art of polyamic acid photosensitive compositions to select an oxydiphthalic dianhydride as disclosed in column 3, line 21 and use it in place of the benzophenone tetracarboxylic dianhydride of the examples and reasonably expect same or similar results as disclosed in the reference.

Motivation is based on the desire to have a photoresist composition that is improved in radiation sensitivity that can give good heat resistance and good edge sharpness.

ALDRICH ET AL discloses a photosensitive composition comprising a polyimide precursor (col. 6, lines 5 - col. 7, lines 48), a photoinitiator (col. 8, line 1-51) and an acryl compound (col. 9, line 20-68). ALDRICH ET AL further teaches that oxydiphthalic anhydride can be used to make the polyamic acid as disclosed in column 7, lines 26-48.

ALDRICH ET AL lacks an explicit example using a polyamic acid as claimed in an example.

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similar results for good heat resistance and good edge sharpness.

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It would have been *prima facie* obvious to one of ordinary skill in the art of photosensitive compositions to substitute the oxydiphthalic acid in column 3, line 21 for the biphenyl tetracarboxylic dianhydride in Example 1 in OHBAYASHI ET AL and reasonably expect same or

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Further it would have been *prima facie* obvious to one of ordinary skill in the art to substitute the oxydiphthalic acid in column 7, line 41 for the biphenyl tetracarboxylic dianhydride in Examples 2 or 30 of ALDRICH ET AL with the reasonable expectation of good image resolution and thermal properties.

Motivation is based on the desire to have a composition which can form patterned images with high heat resistance and good pattern image formation.

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Examiner Chu whose telephone number is (703) 308-2298. The examiner can normally be reached on Monday - Friday from 9:30 am to 6:00 pm.

The fax phone number for this Group is (703) 305-3599.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (703) 308-0661.

John S. Chu

Primary Examiner, Group 1700

J.Chu September 20, 2000